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May 2007

74VHCT573A
Octal D-Type Latch with 3-STATE Outputs

Features

- High speed: t_{PD} = 7.7ns (Typ.) at T_A = 25°C
- High Noise Immunity: V_{IH} = 2.0V, V_{IL} = 0.8V
- Power Down Protection is provided on all inputs and outputs
- Low Noise: V_{OLP} = 1.6V (Max.)
- Low Power Dissipation: I_{CC} = 4μA (Max.) @ T_A = 25°C
- Pin and function compatible with 74HCT573

General Description

The VHCT573A is an advanced high speed CMOS octal latch with 3-STATE output fabricated with silicon gate CMOS technology. It achieves the high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation. This 8-bit D-type latch is controlled by a Latch Enable input (LE) and an Output Enable input ($\overline{OE}$). When the $\overline{OE}$ input is HIGH, the eight outputs are in a high impedance state.

Protection circuits ensure that 0V to 7V can be applied to the input and output(1) pins without regard to the supply voltage. This device can be used to interface 3V to 5V systems and two supply systems such as battery back up. This circuit prevents device destruction due to mismatched supply and input voltages.

Note:

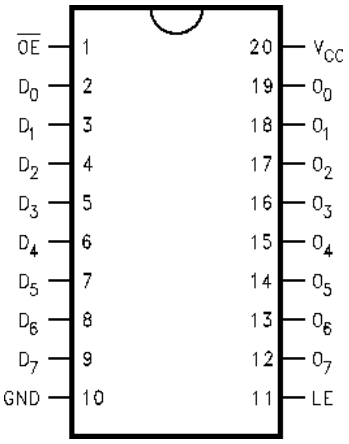
1. Outputs in OFF-State

Ordering Information

Order Number	Package Number	Package Description
74VHCT573AM	M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide
74VHCT573ASJ	M20D	20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74VHCT573AMTC	MTC20	20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide

Surface mount packages are also available on Tape and Reel. Specify by appending the suffix letter “X” to the ordering number. Pb-Free package per JEDEC J-STD-020B.

Connection Diagram

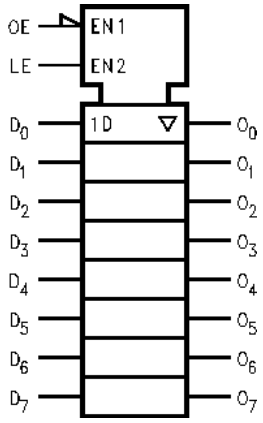


Pin Description

Pin Names	Description
D_0–D_7	Data Inputs
LE	Latch Enable Input
$\overline{OE}$	3-STATE Output Enable Input
O_0–O_7	3-STATE Outputs

Logic Symbol

IEEE/IEC



Functional Description

The VHCT573A contains eight D-type latches with 3-STATE output buffers. When the Latch Enable (LE) input is HIGH, data on the D_n inputs enters the latches. In this condition the latches are transparent, i.e., a latch output will change state each time its D input changes. When LE is LOW the latches store the information that was present on the D inputs, a setup time preceding the HIGH-to-LOW transition of LE. The 3-STATE buffers are controlled by the Output Enable ($\overline{OE}$) input. When $\overline{OE}$ is LOW, the buffers are enabled. When $\overline{OE}$ is HIGH the buffers are in the high impedance mode, but, this does not interfere with entering new data into the latches.

Truth Table

Inputs			Outputs
$\overline{OE}$	LE	D	O_n
L	H	H	H
L	H	L	L
L	L	X	O_0
H	X	X	Z

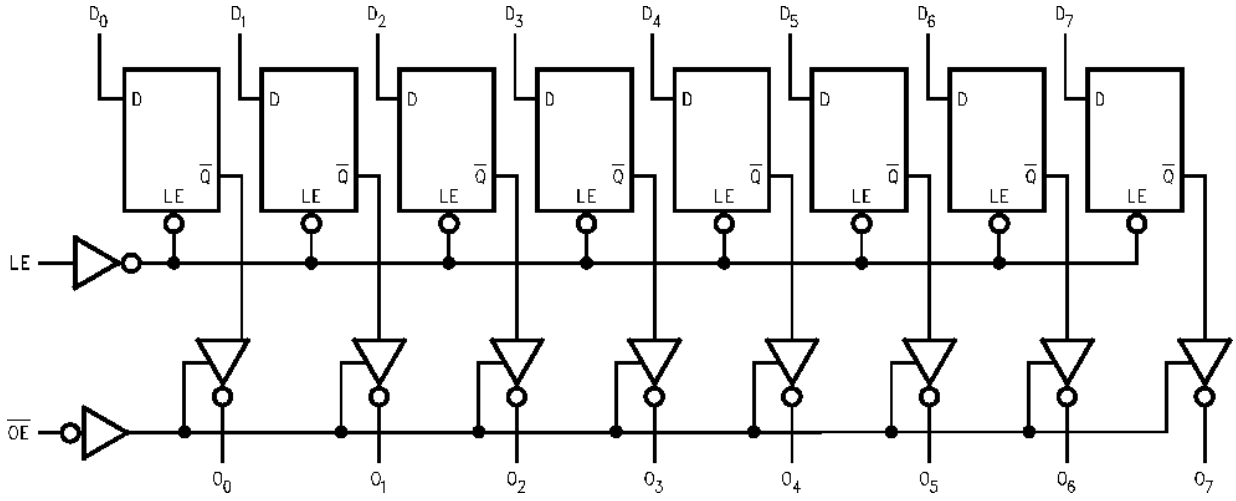
H = HIGH Voltage Level

L = LOW Voltage Level

X = Immaterial

Z = High Impedance

Logic Diagram



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only.

Symbol	Parameter	Rating
V_{CC}	Supply Voltage	–0.5V to +7.0V
V_{IN}	DC Input Voltage	–0.5V to +7.0V
V_{OUT}	DC Output Voltage	
	Note 2	–0.5V to V_{CC} + 0.5V
	Note 3	–0.5V to +7.0V
I_{IK}	Input Diode Current	–20mA
I_{OK}	Output Diode Current(4)	±20mA
I_{OUT}	DC Output Current	±25mA
I_{CC}	DC V_{CC} / GND Current	±75mA
T_{STG}	Storage Temperature	–65°C to +150°C
T_L	Lead Temperature (Soldering, 10 seconds)	260°C

Recommended Operating Conditions(5)

The Recommended Operating Conditions table defines the conditions for actual device operation. Recommended operating conditions are specified to ensure optimal performance to the datasheet specifications. Fairchild does not recommend exceeding them or designing to absolute maximum ratings.

Symbol	Parameter	Rating
V_{CC}	Supply Voltage	4.5V to +5.5V
V_{IN}	Input Voltage	0V to +5.5V
V_{OUT}	Output Voltage	
	Note 2	0V to V_{CC}
	Note 3	0V to 5.5V
T_{OPR}	Operating Temperature	–40°C to +85°C
t_r, t_f	Input Rise and Fall Time, V_{CC} = 5.0V ± 0.5V	0ns/V ~ 20ns/V

Notes:

2. HIGH or LOW state. I_{OUT} absolute maximum rating must be observed.
3. When outputs are in OFF-State or when V_{CC} = 0V.
4. V_{OUT} < GND, V_{OUT} > V_{CC} (Outputs Active).
5. Unused inputs must be held HIGH or LOW. They may not float.

DC Electrical Characteristics

Symbol	Parameter	V_{CC} (V)	Conditions		$T_A = 25°C$			$T_A = -40°C$ to $+85°C$		Units
					Min.	Typ.	Max.	Min.	Max.	
V_{IH}	HIGH Level Input Voltage	4.5			2.0			2.0		V
		5.5			2.0			2.0		
V_{IL}	LOW Level Input Voltage	4.5					0.8		0.8	V
		5.5					0.8		0.8	
V_{OH}	HIGH Level Output Voltage	4.5	$V_{IN} = V_{IH}$ or V_{IL}	$I_{OH} = -50\mu A$	4.40	4.50		4.40		V
				$I_{OH} = -8mA$	3.94			3.80		
V_{OL}	LOW Level Output Voltage	4.5	$V_{IN} = V_{IH}$ or V_{IL}	$I_{OL} = 50\mu A$		0.0	0.1		0.1	V
				$I_{OL} = 8mA$			0.36		0.44	
I_{OZ}	3-STATE Output Off-State Current	5.5	$V_{IN} = V_{IH}$ or V_{IL}, $V_{OUT} = V_{CC}$ or GND				±0.25		±2.5	μA
I_{IN}	Input Leakage Current	0–5.5	$V_{IN} = 5.5V$ or GND				±0.1		±1.0	μA
I_{CC}	Quiescent Supply Current	5.5	$V_{IN} = V_{CC}$ or GND				4.0		40.0	μA
I_{CCT}	Maximum I_{CC}/Input	5.5	$V_{IN} = 3.4V$, Other Inputs = V_{CC} or GND				1.35		1.50	mA
I_{OFF}	Output Leakage Current (Power Down State)	0.0	$V_{OUT} = 5.5V$				0.5		5.0	μA

Noise Characteristics

Symbol	Parameter	V_{CC} (V)	Conditions	$T_A = 25°C$		Units
				Typ.	Limits	
V_{OLP}[6]	Quiet Output Maximum Dynamic V_{OL}	5.0	$C_L = 50pF$	1.2	1.6	V
V_{OLV}[6]	Quiet Output Minimum Dynamic V_{OL}	5.0	$C_L = 50pF$	–1.2	–1.6	V
V_{IHD}[6]	Minimum HIGH Level Dynamic Input Voltage	5.0	$C_L = 50pF$		2.0	V
V_{ILD}[6]	Maximum LOW Level Dynamic Input Voltage	5.0	$C_L = 50pF$		0.8	V

Note:

6. Parameter guaranteed by design.

AC Electrical Characteristics

Symbol	Parameter	V_{CC} (V)	Conditions		T_A = +25°C			T_A = –40°C to +85°C		Units
					Min.	Typ.	Max.	Min.	Max.	
t_{PLH}, t_{PHL}	Propagation Delay Time (LE to O_n)	5.0 ± 0.5		C_L = 15pF		7.7	12.3	1.0	13.5	ns
				C_L = 50pF		8.5	13.3	1.0	14.5	
t_{PLH}, t_{PHL}	Propagation Delay Time (D to O_n)	5.0 ± 0.5		C_L = 15pF		5.1	8.5	1.0	9.5	ns
				C_L = 50pF		5.9	9.5	1.0	10.5	
t_{PZL}, t_{PZH}	3-STATE Output Enable Time	5.0 ± 0.5	R_L = 1kΩ	C_L = 15pF		6.3	10.9	1.0	12.5	ns
				C_L = 50pF		7.1	11.9	1.0	13.5	
t_{PLZ}, t_{PHZ}	3-STATE Output Disable Time	5.0 ± 0.5	R_L = 1kΩ	C_L = 50pF		8.8	11.2	1.0	12.0	ns
t_{OSLH}, t_{OSHL}	Output to Output Skew	5.0 ± 0.5	(7)				1.0		1.0	ns
C_{IN}	Input Capacitance		V_{CC} = Open			4	10		10	pF
C_{OUT}	Output Capacitance		V_{CC} = 5.0V			6				pF
C_{PD}	Power Dissipation Capacitance		(8)			25				pF

Notes:

7. Parameter guaranteed by design. $t_{OSLH} = |t_{PLH\ max} - t_{PLH\ min}|$; $t_{OSHL} = |t_{PHL\ max} - t_{PHL\ min}|$
8. C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation: I_{CC} (Opr.) = C_{PD} • V_{CC} • f_{IN} + I_{CC} / 8 (per F/F). The total C_{PD} when n pcs. of the Latch operates can be calculated by the equation: C_{PD}(total) = 14 + 13n.

AC Operating Requirements

Symbol	Parameter	V_{CC} (V)	T_A = +25°C			T_A = –40°C to +85°C		Units
			Min.	Typ.	Max.	Min.	Max.	
t_W(H)	Minimum Pulse Width (LE)	5.0 ± 0.5	6.5			8.5		ns
t_S	Minimum Set-Up Time	5.0 ± 0.5	1.5			1.5		ns
t_H	Minimum Hold Time	5.0 ± 0.5	3.5			3.5		ns

Physical Dimensions

Dimensions are in millimeters unless otherwise noted.

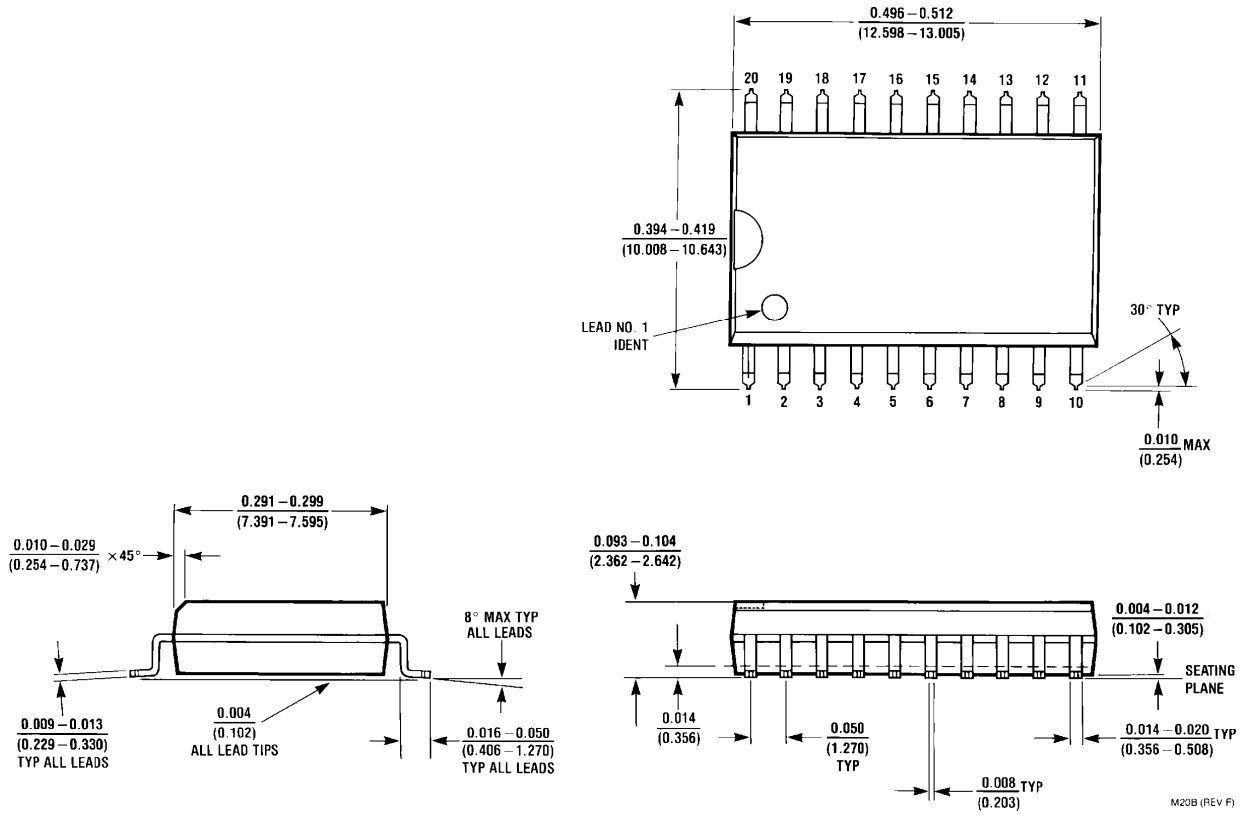


Figure 1. 20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide
Package Number M20B

Physical Dimensions (Continued)

Dimensions are in millimeters unless otherwise noted.

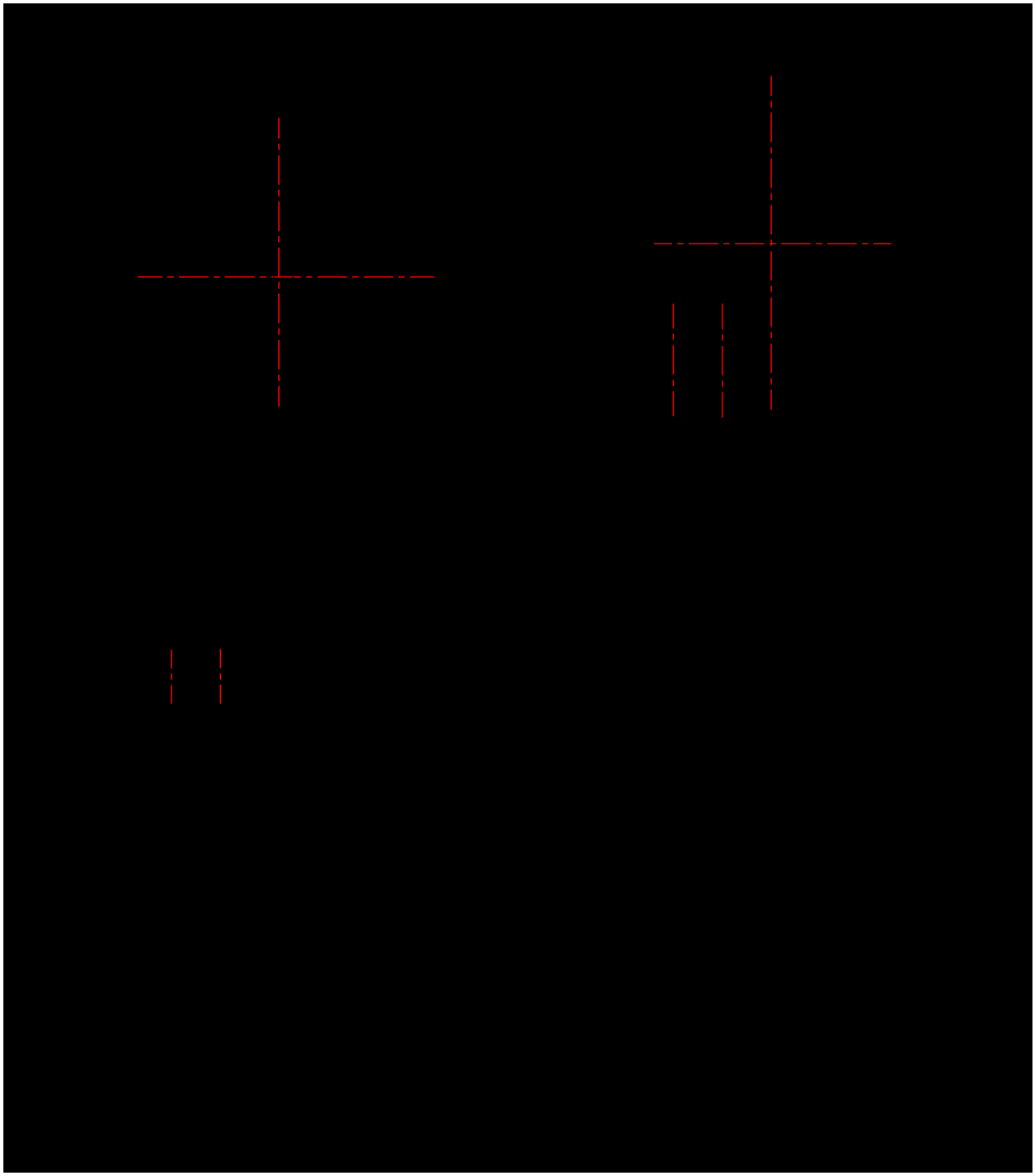


Figure 2. 20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Package Number M20D

Physical Dimensions (Continued)

Dimensions are in millimeters unless otherwise noted.

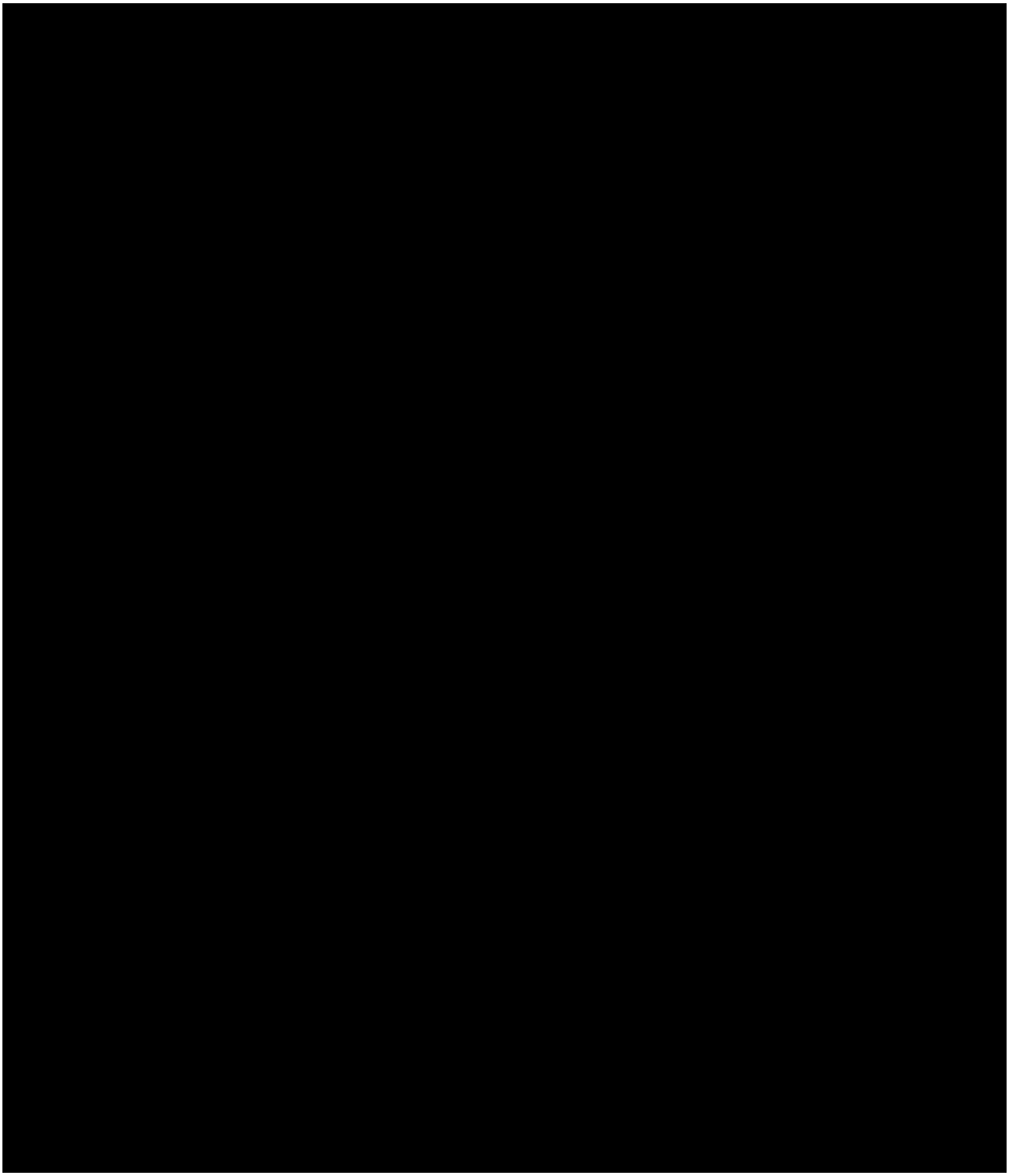
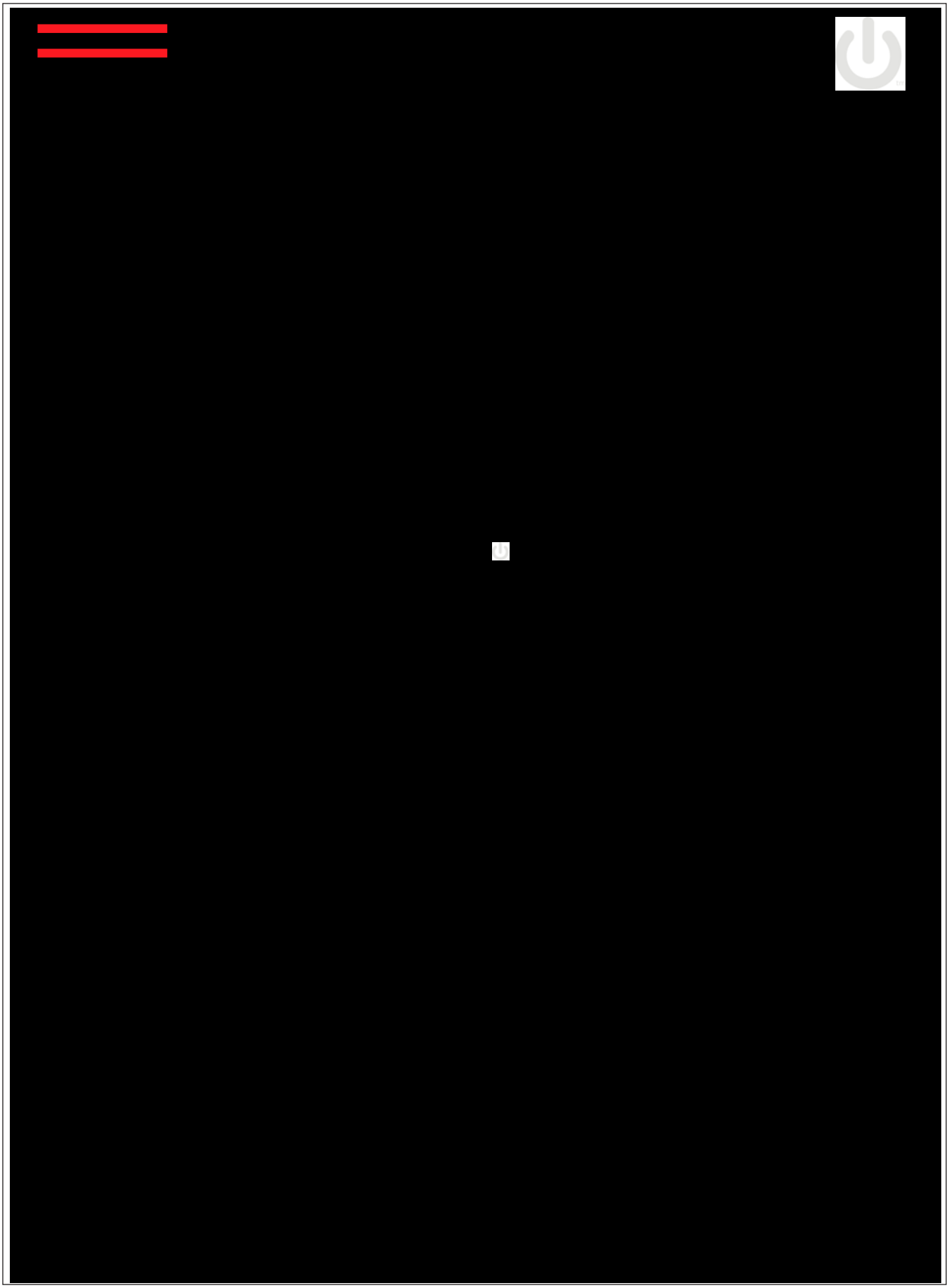


Figure 3. 20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
Package Number MTC20



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